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by MRF326/D

WWW.DZSC.COM The RF Line **NPN Silicon RF** Power Transistor

... designed primarily for wideband large-signal output amplifier stages in the 100 to 500 MHz frequency range.

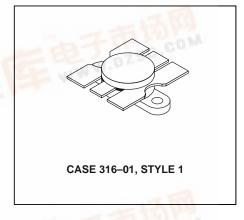
- Guaranteed Performance @ 400 MHz, 28 Vdc Output Power = 40 Watts Minimum Gain = 9.0 dB
- Built–In Matching Network for Broadband Operation
- 100% Tested for Load Mismatch at all Phase Angles with 30:1 VSWR
- Gold Metallization System for High Reliability Applications

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	VCEO	33	Vdc
Collector–Base Voltage	VCBO	60	Vdc
Emitter-Base Voltage	VEBO	4.0	Vdc
Collector Current — Continuous — Peak	IC	4.5 6.0	Adc
Total Device Dissipation @ T _C = 25°C (1) Derate above 25°C	PD	110 0.63	Watts W/°C
Storage Temperature Range	T _{stg}	-65 to +150	°C



40 W, 225 to 400 MHz **CONTROLLED "Q" BROADBAND RF POWER** TRANSISTOR NPN SILICON



THERMAL CHARACTERISTICS

dzsc.com

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	R ₀ JC	1.6	°C/W

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector–Emitter Breakdown Voltage $(I_C = 40 \text{ mAdc}, I_B = 0)$	V(BR)CEO	33	_	—	Vdc
Collector-Emitter Breakdown Voltage (I _C = 40 mAdc, V _{BE} = 0)	V(BR)CES	60	—	-13	Vdc
Emitter–Base Breakdown Voltage $(I_E = 4.0 \text{ mAdc}, I_C = 0)$	V(BR)EBO	4.0	电子	DZSC.	Vdc
Collector–Base Breakdown Voltage ($I_C = 40 \text{ mAdc}, I_E = 0$)	V(BR)CBO	60	AT W. T		Vdc
Collector Cutoff Current (V _{CB} = 30 Vdc, I _E = 0)	СВО	_	_	4.0	mAdc
DN CHARACTERISTICS				-	
DC Current Gain ($I_C = 2.0 \text{ Adc}, V_{CE} = 5.0 \text{ Vdc}$)	hFE	20	50	80	—
DYNAMIC CHARACTERISTICS				-	
Output Capacitance ($V_{CB} = 28 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz}$)	C _{ob}	—	45	60	pF
IOTE:	•		•		(continue

The device is designed for RF operation. The total device dissipation rating applies only when the device is operated as an RF amplifier.



Characteristic	Symbol	Min	Тур	Max	Unit
FUNCTIONAL TESTS (Figure 1)					
Common–Emitter Amplifier Power Gain (V _{CC} = 28 Vdc, P _{out} = 40 W, f = 400 MHz, I _C Max = 2.85 Adc)	GPE	9.0	11	—	dB
Collector Efficiency (V _{CC} = 28 Vdc, P _{out} = 40 W, f = 400 MHz, I _C Max = 2.85 Adc)	η	50	_	-	%
Load Mismatch (V _{CC} = 28 Vdc, P _{OUt} = 40 W CW, f = 400 MHz, VSWR = 30:1 All Phase Angles)	Ψ	No Degradation in Output Power			

ELECTRICAL CHARACTERISTICS — continued (T_C = 25°C unless otherwise noted.)

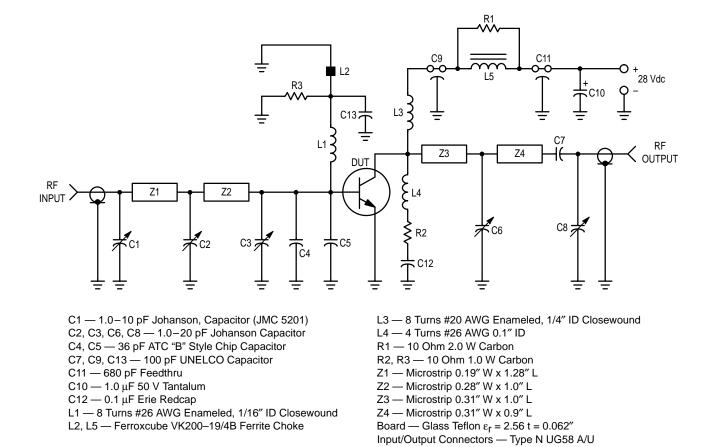


Figure 1. 400 MHz Test Amplifier

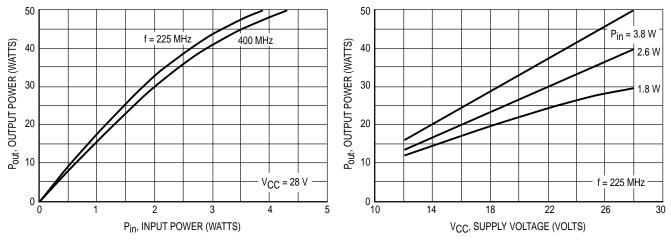




Figure 3. Output Power versus Supply Voltage

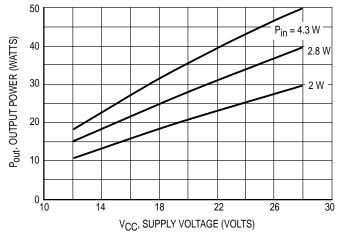
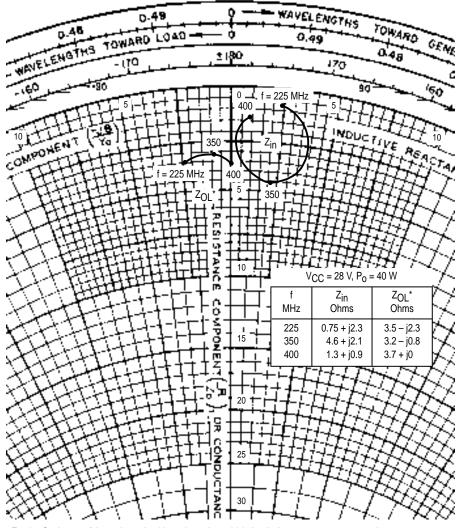


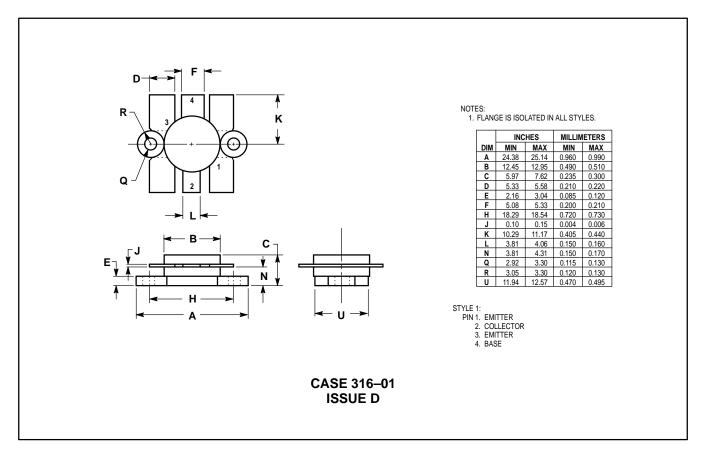
Figure 4. Output Power versus Supply Voltage f = 400 MHz



Z_{OL}* = Conjugate of the optimum load impedance into which the device output operates at a given output power, voltage and frequency.

Figure 5. Series Equivalent Input–Output Impedance

PACKAGE DIMENSIONS



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